Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2992

Chopper Regulator, DC-DC Converter and Motor Drive Applications

Low drain-source ON resistance : R_{DS} (ON) = 2.2 Ω (typ.)
 High forward transfer admittance : |Y_{fs}| = 0.9 S (typ.)
 Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 200 V)
 Enhancement mode : V_{th} = 2.0 to 3.5 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	200	V
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	200	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	DC (Note 1)	I _D	1	Α
	Pulse (Note 1)	I _{DP}	3	Α
Drain power dissipation	١	P_{D}	0.5	W
Drain power dissipation (Note 2)		P_{D}	1.5	W
Single pulse avalanche	e energy (Note 3)	E _{AS}	36	mJ
Avalanche current		I _{AR}	1	Α
Repetitive avalanche e	nergy (Note 4)	E _{AR}	0.05	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55~150	°C

1. GATE
2. DRAIN
3. SOURCE

JEDEC

JEITA

4.6MAX.

1,6MAX.

0.4±0.05

0.4±0.05

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

1.5±0.1

Weight: 0.05 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient	R _{th (ch-a)}	250	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Mounted on a ceramic substrate (25.4 mm × 25.4 mm × 0.8 mm)

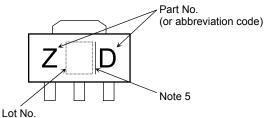
Note 3: V_{DD} = 50 V, T_{ch} = 25°C (initial), L = 56.7 mH, R_G = 25 Ω , I_{AR} = 1 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

Marking



Note 5: A line to the right of a Lot No. identifies the indication of product Labels.

Without a line: [[Pb]]/INCLUDES > MCV

With a line: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

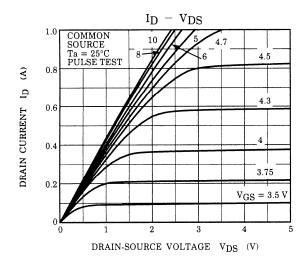
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

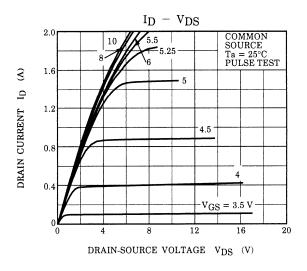
Electrical Characteristics (Ta = 25°C)

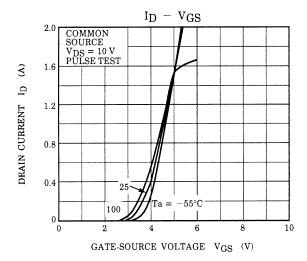
Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ
Drain cut-off cu			_	_	100	μA	
Drain-source br voltage	reakdown	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	200	_	_	٧
Gate threshold	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	3.5	V
Drain-source O	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 0.5 A	_	2.2	3.5	Ω
Forward transfe	r admittance	Y _{fs}	V _{DS} = 10 V, I _D = 0.5 A	0.5	0.9	_	S
Input capacitance		C _{iss}		_	90	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	10	_	pF
Output capacitance		Coss			30	_	
Switching time	Rise time	t _r	V_{GS} V_{OV} V_{OUT} V_{OUT} V_{OUT} V_{DD} V_{DD}	_	9	_	
	Turn-on time	t _{on}		_	17	_	no
	Fall time	t _f		_	16	_	ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\rm W} = 10 \mu \rm s$	_	45	_	
Total gate charge (gate-source plus gate-drain)		Qg		1	3.0		nC
Gate-source charge		Q _{gs}	$V_{DD} \approx 160 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$	_	1.8	_	
Gate-drain ("miller") charge		Q _{gd}			1.2		

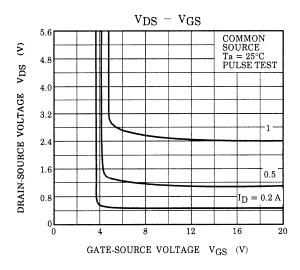
Source-Drain Ratings and Characteristics (Ta = 25°C)

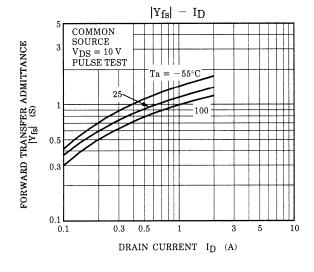
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	1	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	3	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 1 A, V _{GS} = 0 V	_	_	-1.5	V
Reverse recovery time	t _{rr}	I _{DR} = 1 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs	_	85	_	ns
Reverse recovery charge	Q _{rr}	1		190		nC

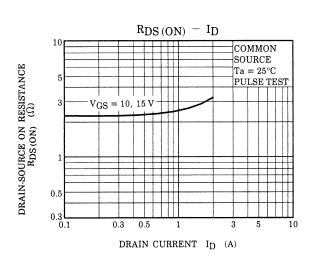


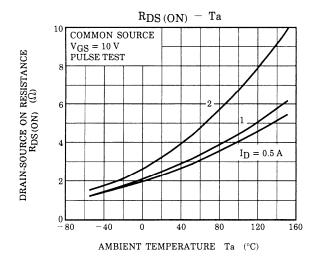


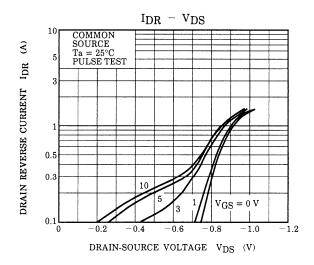


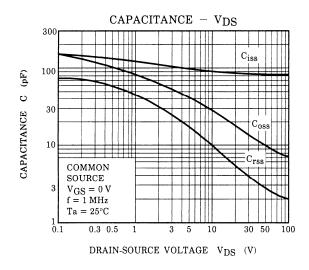


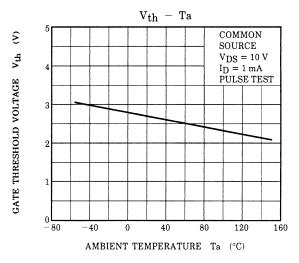


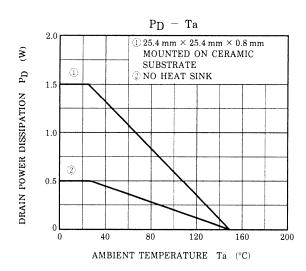




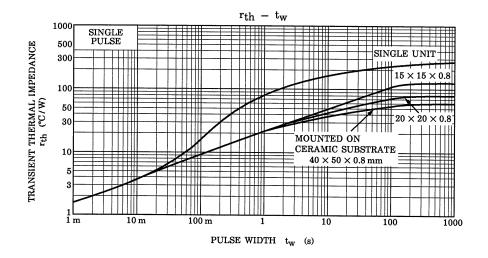


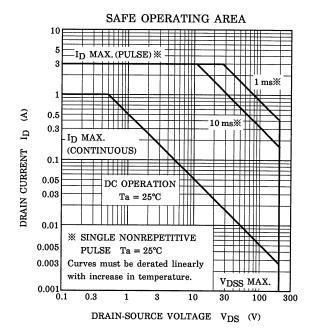


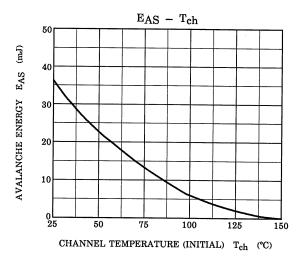


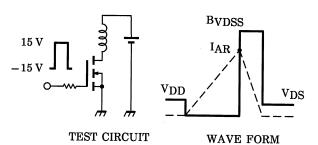


4









$$\begin{aligned} &RG = 25~\Omega \\ &V_{DD} = 50~V,~L = 56.7~mH \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BV_{DSS}}{BV_{DSS} - V_{DD}} \right)$$

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6